

600V N-Channel Super Junction MOSFET

Voltage	600 V	R _{dson}	190 mΩ
Current	20 A	Q _g	40 nC

Feature:

- R_{DSON} Max, V_{GS}@10V: 190mΩ
- Easy to use/ drive
- High Speed Switching and Low R_{DSON}
- 100% Avalanche Tested
- 100% R_g Tested
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: ITO-220AB-F package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.068 ounces, 2 grams

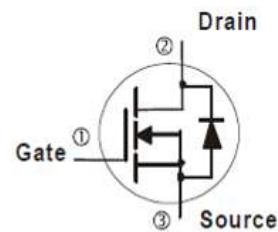
Application

- PFC, TV Power, PC Power, PD Charger, Adapter, Server, UPS

Absolute Maximum Ratings (T_A = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage @ T _{jmax}	V _{DS}	650	V
Drain-Source Voltage	V _{DS}	600	
Gate-Source Voltage	V _{GS}	±30	A
Continuous Drain Current	I _D	20	
T _C =25°C		13	A
Pulsed Drain Current	I _{DM}	60	
T _C =25°C			mJ
Single Pulse Avalanche Energy	E _{AS}	420	
MOSFET dv/dt ruggedness	dv/dt	50	V/ns
Power Dissipation	P _D	38	W
T _C =100°C		15	
Insulation Withstand Voltage for ITO-220AB-F	V _{ISO}	3.5	kV
Operating Junction and Storage Temperature Range	T _{J,TSTG}	-55~150	°C

ITO-220AB-F



Thermal Characteristics

PARAMETER	SYMBOL	MAXIMUM	UNITS
Thermal Resistance	R _{θJC}	3.3	°C/W
	R _{θJA}	62.5	°C/W

Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	600	670	-	V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	2	3.1	4	
Drain-Source On-State Resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=9.5\text{A}$ (Note 1)	-	157	190	$\text{m}\Omega$
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=600\text{V}, V_{\text{GS}}=0\text{V}$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 30\text{V}, V_{\text{DS}}=0\text{V}$	-	-	± 100	nA
Transfer characteristics	g_{fs}	$V_{\text{DS}}=20\text{V}, I_{\text{D}}=20\text{A}$	-	18	-	S
Dynamic (Note 5)						
Total Gate Charge	Q_g	$V_{\text{DS}}=480\text{V}, I_{\text{D}}=20\text{A}, V_{\text{GS}}=10\text{V}$	-	40	-	nC
Gate-Source Charge	Q_{gs}		-	9	-	
Gate-Drain Charge	Q_{gd}		-	17	-	
Input Capacitance	C_{iss}	$V_{\text{DS}}=400\text{V}, V_{\text{GS}}=0\text{V}, f=250\text{kHz}$	-	1410	-	pF
Output Capacitance	C_{oss}		-	50	-	
Reverse Transfer Capacitance	C_{rss}		-	13	-	
Effective Output Capacitance Energy Related	$C_{\text{o(er)}}$	$V_{\text{DS}}=0\text{V}$ to 480V , $V_{\text{GS}}=0\text{V}, f=250\text{kHz}$ (Note 4)	-	68	-	
Turn-On Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=300\text{V}, I_{\text{D}}=20\text{A}, V_{\text{GS}}=10\text{V}, R_{\text{G}}=25\Omega$ (Note 2)	-	51	-	ns
Turn-On Rise Time	t_r		-	81	-	
Turn-Off Delay Time	$t_{\text{d(off)}}$		-	174	-	
Turn-Off Fall Time	t_f		-	78	-	
Gate Resistance	R_g	$f=1.0\text{MHz}$	-	8	-	Ω
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_s		-	-	20	A
Diode Forward Voltage	V_{SD}	$I_s=20\text{A}, V_{\text{GS}}=0\text{V}$	-	-	1.4	V
Reverse Recovery Charge	Q_{rr}	$I_s=20\text{A}$ $dI/dt=100\text{A}/\mu\text{s}$	-	6.5	-	μC
Reverse Recovery Time	T_{rr}		-	380	-	ns

NOTES :

1. Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. R_{\thetaJA} is the sum of the junction-to-case and case-to-ambient thermal resistance.
4. $C_{\text{o(er)}}$ is a capacitance that gives the same stored energy as C_{oss} while V_{DS} is rising from 0V to 80% $V_{(\text{BR})\text{DSS}}$
5. Guaranteed by design, not subject to production testing

TYPICAL CHARACTERISTIC CURVES

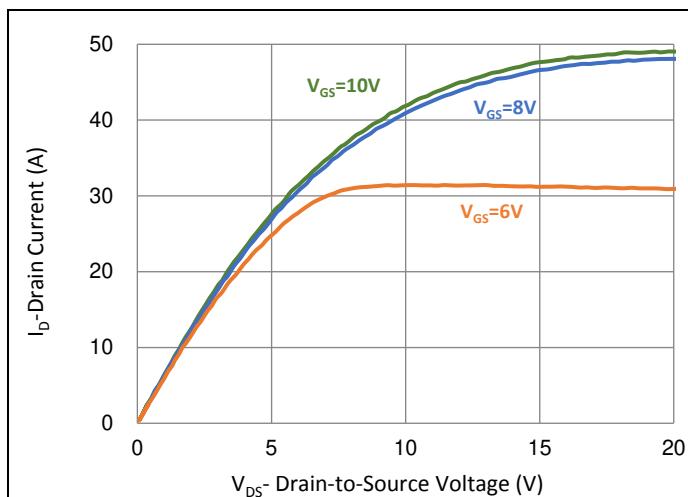


Fig.1 Output Characteristics

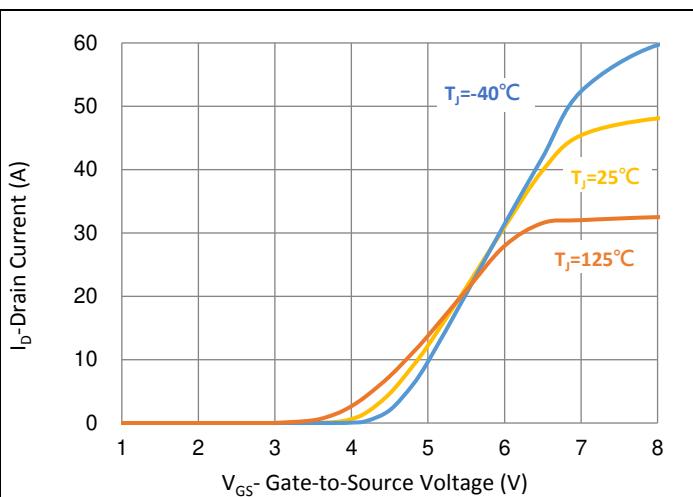


Fig.2 Transfer Characteristics

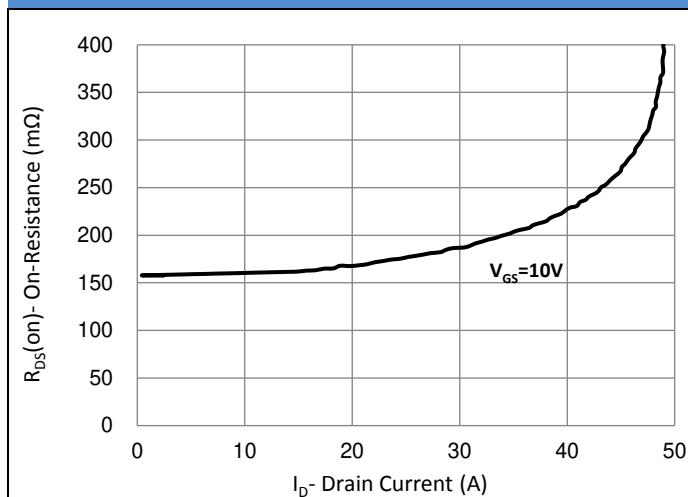


Fig.3 On-Resistance vs. Drain Current

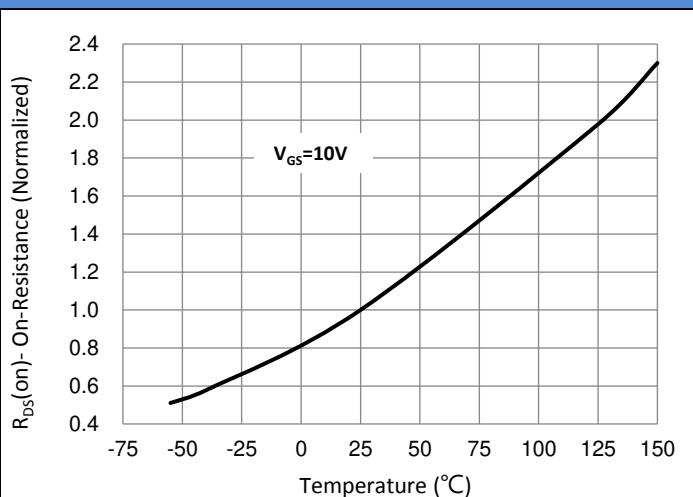


Fig.4 On-Resistance vs. Junction Temperature

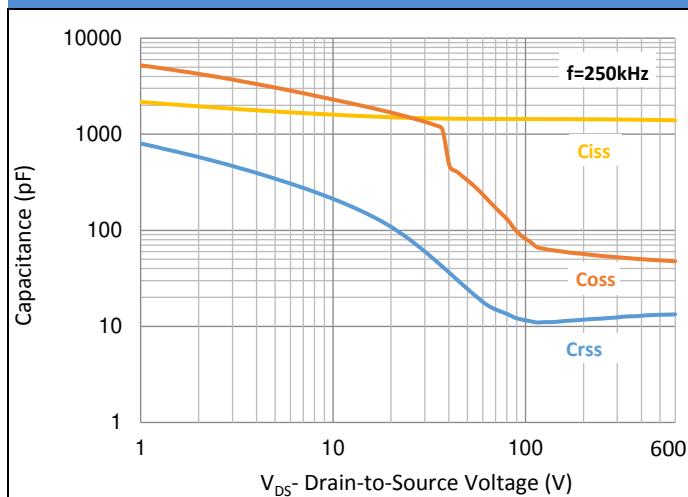


Fig.5 Capacitance vs. Drain-Source Voltage

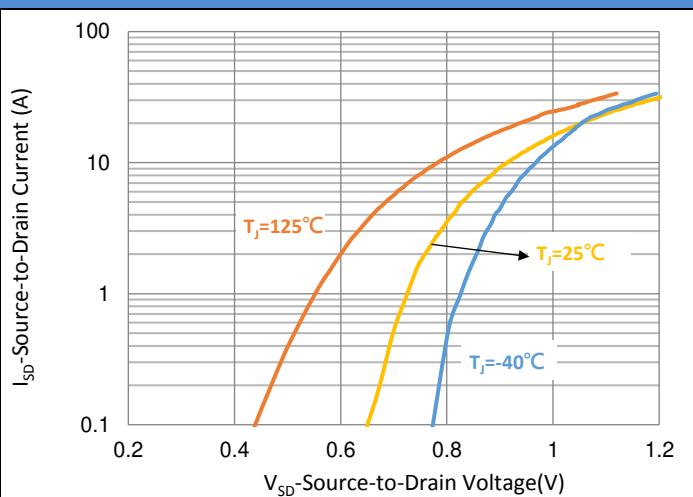


Fig.6 Source-Drain Diode Forward Voltage

TYPICAL CHARACTERISTIC CURVES

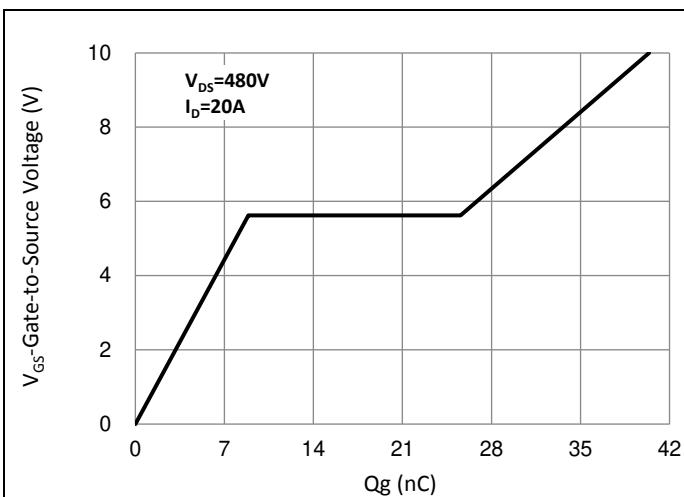


Fig.7 Gate-Charge Characteristics

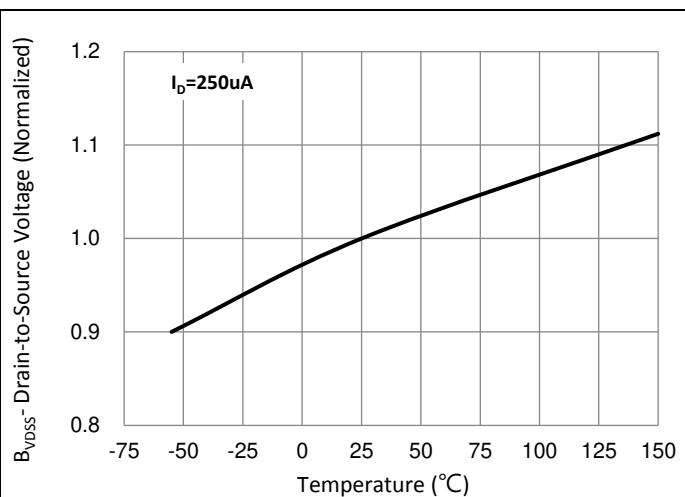


Fig.8 Breakdown Voltage Variation vs. Temperature

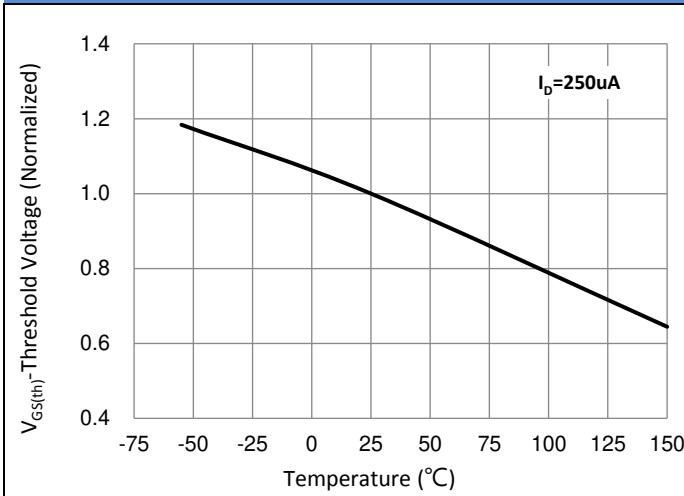


Fig.9 Threshold Voltage Variation with Temperature

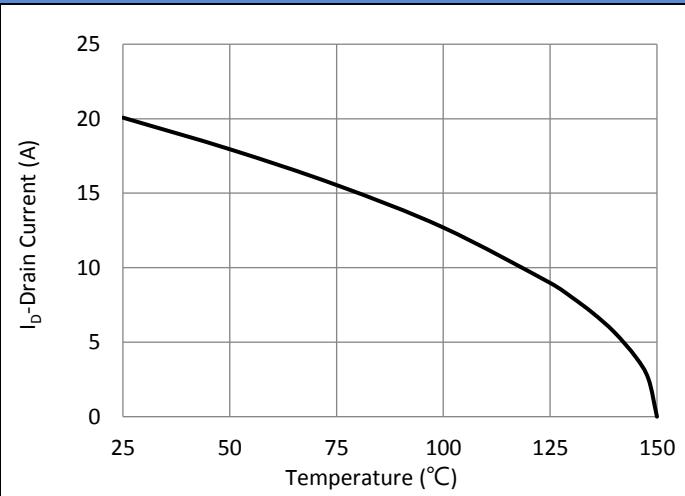


Fig.10 Drain Current vs. Case Temperature

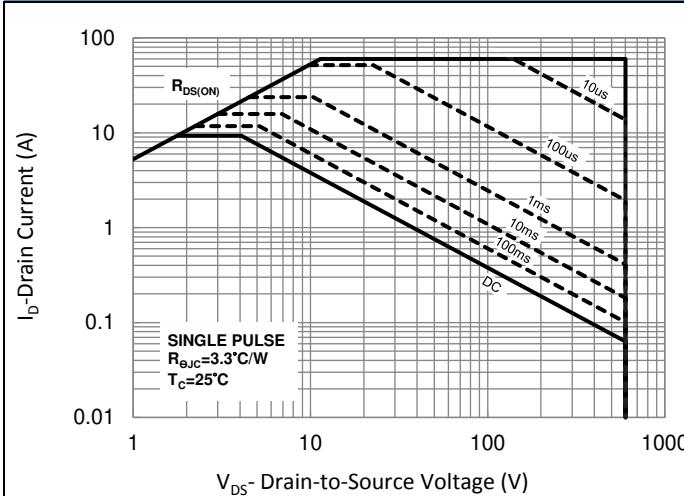


Fig.11 Maximum Safe Operating Area

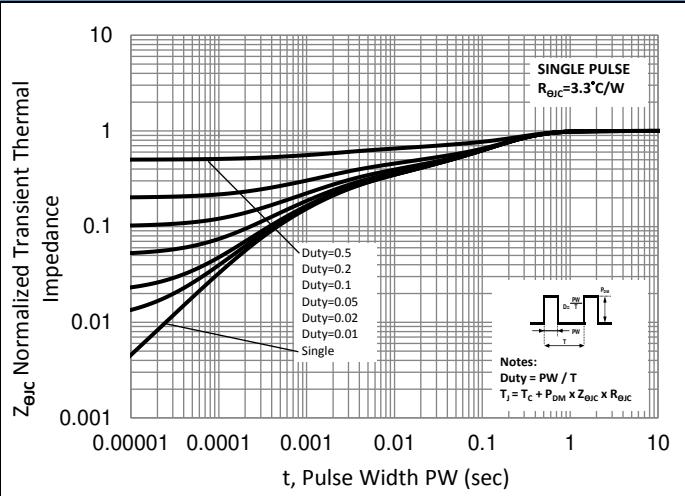


Fig.12 Normalized Transient Thermal Impedance

TYPICAL CHARACTERISTIC CURVES

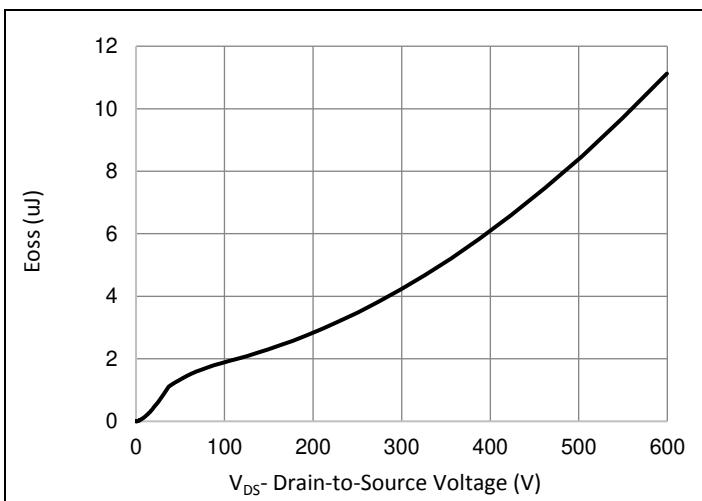
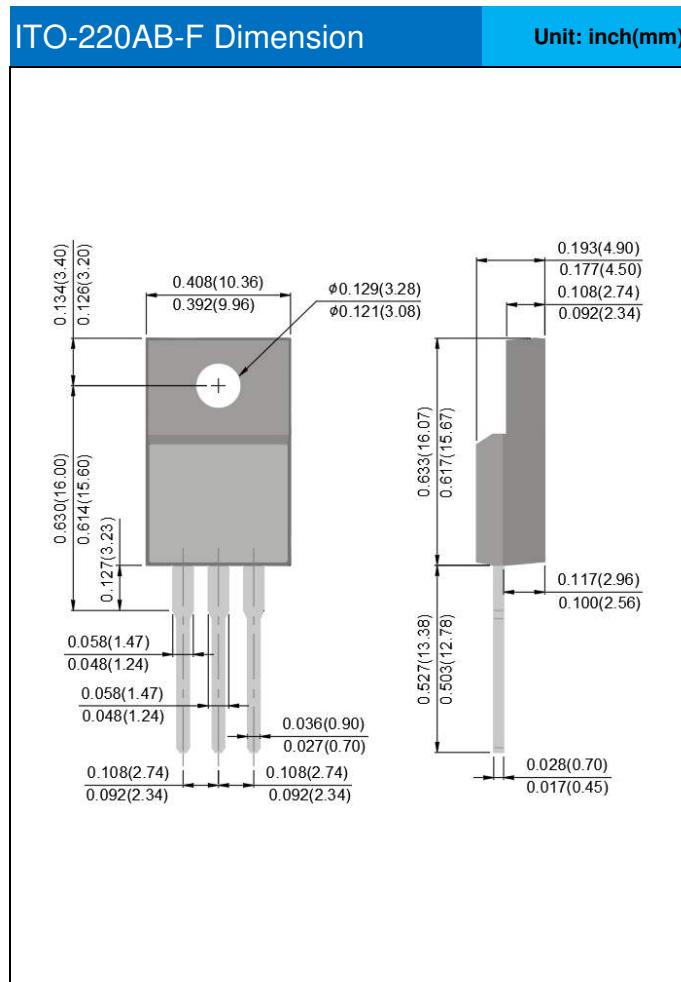


Fig.13 Typ. Coss Stored Energy

Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJMF190N60E1	ITO-220AB-F	50pcs / Tube	190N60E1

Packaging Information



Marking Diagram

PJ
190N60E1
YWLL X

- PJ** = Year Code
- W** = Week Code (A~Z)
- LL** = Lot Code (00~99)
- x** = Production Line Code

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